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IN THE UNITED STATES PATENT & TRADEMARK OFFICE SEP 26 2002

IN RE APPLICATION OF:

: TECHNOLOGY CENTER 2800

TATSUYA OHGURO

: EXAMINER: DANA FARAHANI

SERIAL NO. : 09/409,393

:

FILED: FEBRUARY 28, 2002

: GROUP ART UNIT: 2814

FOR: SEMICONDUCTOR DEVICE
APPLIED TO A VARIABLE
CAPACITANCE CAPACITOR
AND AMPLIFIER

:

:

*HS/Amelt R
Approved
10/1/02*

AMENDMENT

ASSISTANT COMMISSIONER FOR PATENTS
WASHINGTON, D.C. 20231

SIR:

In response to the Official Office Action dated June 24, 2002, please amend the
above-identified patent application as follows:

IN THE CLAIMS

**Please amend Claim 7 as shown in clean form below. A marked-up copy of the
amended claim is attached.**

7. (Amended) A semiconductor device comprising:

a semiconductor substrate;

a first conductivity type well area formed in a surface area of the semiconductor
substrate;

a plurality of element isolation areas formed in the well area;

*A1
Sub B2*